January 2014

# FAN6300A / FAN6300H Highly Integrated Quasi-Resonant Current Mode PWM Controller

#### Features

High-Voltage Startup

FAIRCHILD

- Quasi-Resonant Operation
- Cycle-by-Cycle Current Limiting
- Peak-Current-Mode Control
- Leading-Edge Blanking (LEB)
- Internal Minimum toFF
- Internal 5 ms Soft-Start
- Over Power Compensation
- GATE Output Maximum Voltage
- Auto-Recovery Over-Current Protection(FB Pin)
- Auto-Recovery Open-Loop Protection(FB Pin)
- VDD Pin and Output Voltage (DET Pin) OVP Latched
- Low Frequency Operation (below 100 kHz) for FAN6300A
- High Frequency Operation (up to 190 kHz) for FAN6300H

#### Applications

- AC/DC NB Adapters
- Open-Frame SMPS

#### Description

The highly integrated FAN6300A/H of PWM controller provides several features to enhance the performance of flyback converters. FAN6300A is applied on quasi-resonant flyback converters where maximum operating frequency is below 100 kHz. FAN6300H is suitable for high-frequency operation (up to 190 kHz). A built-in HV startup circuit can provide more startup current to reduce the startup time of the controller. Once the  $V_{DD}$  voltage exceeds the turn-on threshold voltage, the HV startup function is disabled immediately to reduce power consumption. An internal valley voltage detector ensures power system operates at quasi-resonant operation over a wide-range of line voltage and any load conditions, as well as reducing switching loss to minimize switching voltage on drain of power MOSFET.

To minimize standby power consumption and light-load efficiency, a proprietary green-mode function provides off-time modulation to decrease switching frequency and perform extended valley voltage switching to keep to a minimum switching voltage. The operating frequency is limited by minimum  $t_{off}$  time, which is 38 µs to 8 µs in FAN6300A and 13 µs to 3 µs in FAN6300H, so FAN6300H can operate at higher switching frequency than FAN6300A.

FAN6300A/H controller also provides many protection functions. Pulse-by-pulse current limiting ensures the fixed-peak current limit level, even when a short circuit occurs. Once an open-circuit failure occurs in the feedback loop, the internal protection circuit disables PWM output immediately. As long as  $V_{DD}$  drops below the turn-off threshold voltage, the controller also disables PWM output. The gate output is clamped at 18 V to protect the power MOS from high gate-source voltage conditions. The minimum  $t_{OFF}$  time limit prevents the system frequency from being too high. If the DET pin triggers OVP, internal OTP is triggered and the power system enters latch-mode until AC power is removed.

The FAN6300A/H controller is available in the 8-pin Small Outline Package (SOP).

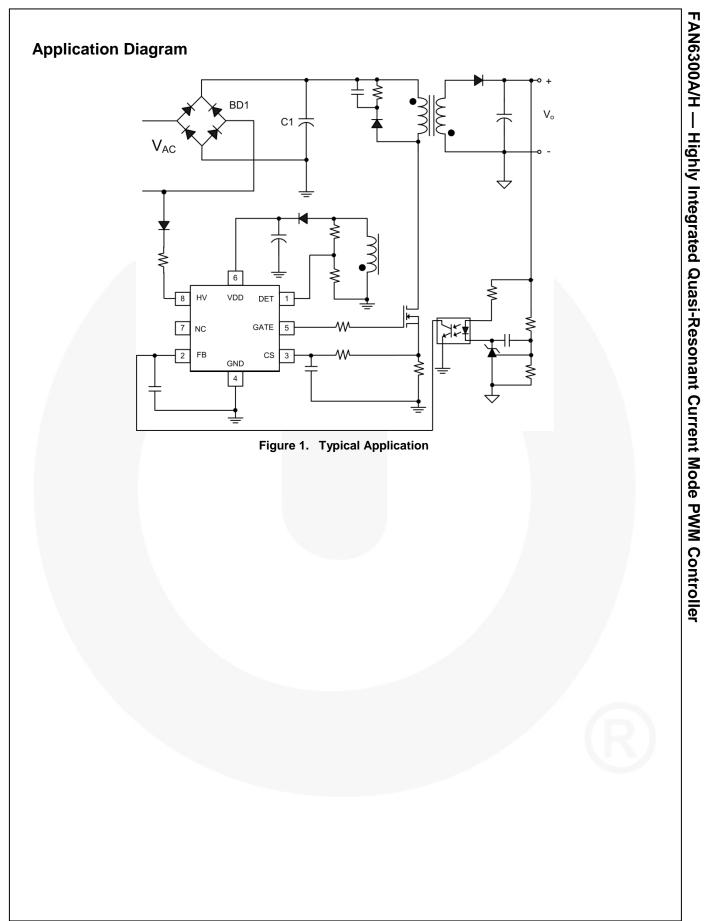
#### **Ordering Information**

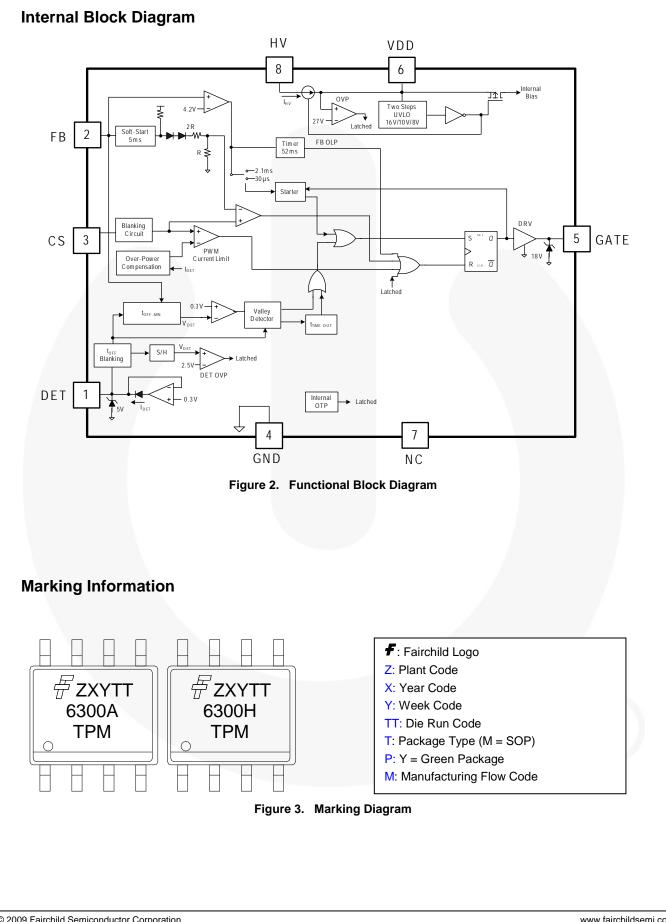
Part Number	Operating Temperature Range	Package	Packing Method	
FAN6300AMY	-40°C to +125°C	8 Load Small Outline Deckage (SOD)	Topo & Dool	
FAN6300HMY	-40 C 10 +125 C	8-Lead, Small Outline Package (SOP)	Tape & Reel	

🥙 For Fairchild's definition of Eco Status, please visit: <u>http://www.fairchildsemi.com/company/green/rohs\_green.html</u>

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### **Pin Configuration**

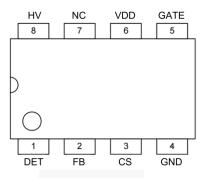


Figure 4. Pin Configuration

### **Pin Definitions**

Pin #	Name	Description
1	DET	<ul> <li>This pin is connected to an auxiliary winding of the transformer via resistors of the divider for the following purposes:</li> <li>Generates a ZCD signal once the secondary-side switching current falls to zero.</li> <li>Produces an offset voltage to compensate the threshold voltage of the peak current limit to provide a constant power limit. The offset is generated in accordance with the input voltage when PWM signal is enabled.</li> <li>Detects the valley voltage of the switching waveform to achieve the valley voltage switching and minimize the switching losses.</li> <li>A voltage comparator and a 2.5 V reference voltage develop a output OVP protection. The ratio of the divider decides what output voltage to stop gate, as an optical coupler and secondary shunt regulator are used.</li> </ul>
2	FB	The feedback pin should to be connected to the output of the error amplifier for achieving the voltage control loop. The FB should be connected to the output of the optical coupler if the error-amplifier is equipped at the secondary-side of the power converter. For the primary-side control application, FB is applied to connect a RC network to the ground for feedback-loop compensation. The input impedance of this pin is a 5 k $\Omega$ equivalent resistance. A 1/3 attenuator connected between the FB and the PWM circuit is used for the loop-gain attenuation. FAN6300A/H performs an open-loop protection once the FB voltage is higher than a threshold voltage (around 4.2 V) more than 55 ms.
3	CS	Input to the comparator of the over-current protection. A resistor senses the switching current and the resulting voltage is applied to this pin for the cycle-by-cycle current limit.
4	GND	The power ground and signal ground. A 0.1 $\mu F$ decoupling capacitor placed between VDD and GND is recommended.
5	GATE	Totem-pole output generates the PWM signal to drive the external power MOSFET. The clamped gate output voltage is 18 V.
6	VDD	Power supply. The threshold voltages for startup and turn-off are 16 V and 10 V, respectively. The startup current is less than 20 $\mu$ A and the operating current is lower than 4.5 mA.
7	NC	No connect
8	HV	High-voltage startup.

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit
V <sub>DD</sub>	DC Supply Voltage		30	V
V <sub>HV</sub>	HV		500	V
V <sub>H</sub>	GATE	-0.3	25.0	V
VL	V <sub>FB</sub> , V <sub>CS</sub> , V <sub>DET</sub>	-0.3	7.0	V
PD	Power Dissipation		400	mW
TJ	Operating Junction Temperature		+150	°C
T <sub>STG</sub>	Storage Temperature Range	-55	+150	°C
TL	Lead Temperature (Soldering 10 Seconds)		+270	°C
ESD	Human Body Model, JEDEC:JESD22-A114		3.0	κv
ESD	Charged Device Model, JEDEC:JESD22-C101		1.5	κv

Notes:

1. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device.

2. All voltage values, except differential voltages, are given with respect to GND pin.

#### **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
TA	Operating Ambient Temperature		-40		+125	°C

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VDI	D-OVP	V <sub>DD</sub> Over-Voltage Protection (Latch-Off)		26	27	28	
t <sub>VDI</sub>	D-OVP	V <sub>DD</sub> OVP Debounce Time		100	150	200	
I <sub>DD-</sub>	LATCH	V <sub>DD</sub> OVP Latch-Up Holding Current	V <sub>DD</sub> =5 V		42		
HV S	Startup	Current Source Section					
V <sub>H</sub>	V-MIN	Minimum Startup Voltage on Pin HV				50	
I	HV	Supply Current Drawn from Pin HV	V <sub>AC</sub> =90 V(V <sub>DC</sub> =120V) V <sub>DD</sub> =0 V	1.5		4.0	
IH	V-LC	Leakage Current After Startup	HV=500 V, V <sub>DD</sub> =V <sub>DD-OFF</sub> +1 V		1	20	
Feed	lback Ir	nput Section					
,	Av	Input-Voltage to Current Sense Attenuation	$A_{V} = \Delta V_{CS} / \Delta V_{FB}$ $0 < V_{CS} < 0.9$	1/2.75	1/3.00	1/3.25	
Z	<b>Z</b> FB	Input Impedance		3	5	7	
ļ	oz	Bias Current	FB=V <sub>OZ</sub>		1.2	2	
V	/ <sub>oz</sub>	Zero Duty-Cycle Input Voltage		0.8	1.0	1.2	
VF	B-OLP	Open Loop Protection Threshold Voltage		3.9	4.2	4.5	
t <sub>D</sub> .	-OLP	Debounce Time for Open-Loop/Overload Protection		46	52	62	
t	ss	Internal Soft-Start Time			5		

Conditions

V<sub>DD</sub>=V<sub>DD-ON</sub>-0.16 V

V<sub>DD</sub>=15 V, f<sub>S</sub>=60 KHz,

V<sub>DD</sub>=15 V, f<sub>S</sub>=2 KHz,

V<sub>DD</sub>=V<sub>DD-PWM-OFF</sub>-0.5 V

GATE Open

C<sub>L</sub>=2 nF

C<sub>L</sub>=2 nF

Min.

15

9

7

70

Typ.

16

10

8

10

4.5

80

Max.

25

17

11

9

20

5.5

3.5

90

Unit

V

V

V

V

μA

mΑ

mΑ

μA

V μs μΑ

V mΑ

μA

V/V

KΩ mΑ V V

ms

ms

#### **Electrical Characteristics**

Symbol

**V**<sub>DD</sub> Section

VOP

V<sub>DD-ON</sub>

 $V_{\text{DD-PWM-OFF}}$ 

 $V_{\text{DD-OFF}}$ 

 $I_{DD-ST}$ 

IDD-OP

IDD-GREEN

IDD-PWM-OFF

Unless otherwise specified,  $V_{DD}$ =10~25 V,  $T_A$ =-40°C~125°C ( $T_A$ =T<sub>J</sub>).

Green-Mode Operating Supply Current

Operating Current at PWM-Off Phase

Continuously Operating Voltage

Turn-On Threshold Voltage

PWM Off Threshold Voltage

Turn-Off Threshold Voltage

Startup Current

(Average)

**Operating Current** 

Parameter

Continued on the following page ...

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
DET Pin OV	/P and Valley Detection Section				II	
V <sub>DET-OVP</sub>	Comparator Reference Voltage		2.45	2.50	2.55	V
Av	Open-Loop Gain <sup>(3)</sup>			60		dB
Bw	Gain Bandwidth <sup>(3)</sup>			1		MHz
V <sub>V-HIGH</sub>	Output High Voltage		4.5			V
V <sub>V-LOW</sub>	Output Low Voltage				0.5	V
t <sub>DET-OVP</sub>	Output OVP (Latched) Debounce Time		100	150	200	μs
IDET-SOURCE	Maximum Source Current	V <sub>DET</sub> =0 V			1	mA
V <sub>DET-HIGH</sub>	Upper Clamp Voltage	I <sub>DET</sub> =-1 mA			5	V
V <sub>DET-LOW</sub>	Lower Clamp Voltage	I <sub>DET</sub> =1 mA	0.1	0.3		V
tvalley-delay	Delay Time from Valley-Signal Detected to Output Turn-On <sup>(3)</sup>			200		ns
	Leading-Edge-Blanking Time for DET when	FAN6300A		4.0		μs
toff-bnk	Leading-Edge-Blanking Time for DET when PWM MOS Turns Off <sup>(3)</sup>	FAN6300H		1.5		
	Time-Out after t <sub>OFF-MIN</sub>	FAN6300A		9		μs
t <sub>TIME-OUT</sub>		FAN6300H		5		
Oscillator S	Section		•		L L	
t <sub>ON-MAX</sub>	Maximum On-Time		38	45	54	μs
	Minimum Off-Time	V <sub>FB</sub> ≧V <sub>N,</sub> FAN6300A		8		μs
toff-MIN		V <sub>FB</sub> ≧V <sub>N</sub> FAN6300H		3		μs
OFF-MIN		V <sub>FB</sub> =V <sub>G</sub> FAN6300A		38		μs
		V <sub>FB</sub> =V <sub>G</sub> FAN6300H		13		μs
V <sub>N</sub>	Beginning of Green-On Mode at FB Voltage Level		1.95	2.10	2.25	V
$V_{G}$	Beginning of Green-Off Mode at FB Voltage Level		1.0	1.2	1.4	V
$\Delta V_{FBG}$	Green-Off Mode V <sub>FB</sub> Hysteresis Voltage		0.05	0.10	0.20	V
t	Start Timer (Time-Out Timer)	$V_{FB} < V_G$	1.8	2.1	2.4	ms
<b>t</b> STARTER	Start Timer (Time-Out Timer)	$V_{FB}$ > $V_{FB-OLP}$	25	30	45	μs
Output Sec	tion					
V <sub>OL</sub>	Output Voltage Low	V <sub>DD</sub> =15 V, I <sub>O</sub> =150 mA			1.5	V
V <sub>OH</sub>	Output Voltage High	V <sub>DD</sub> =12 V, I <sub>O</sub> =150 mA	7.5			V
t <sub>R</sub>	Rising Time			145	200	ns
t <sub>F</sub>	Falling Time			55	120	ns
V <sub>CLAMP</sub>	Gate Output Clamping Voltage		16.7	18.0	19.3	V

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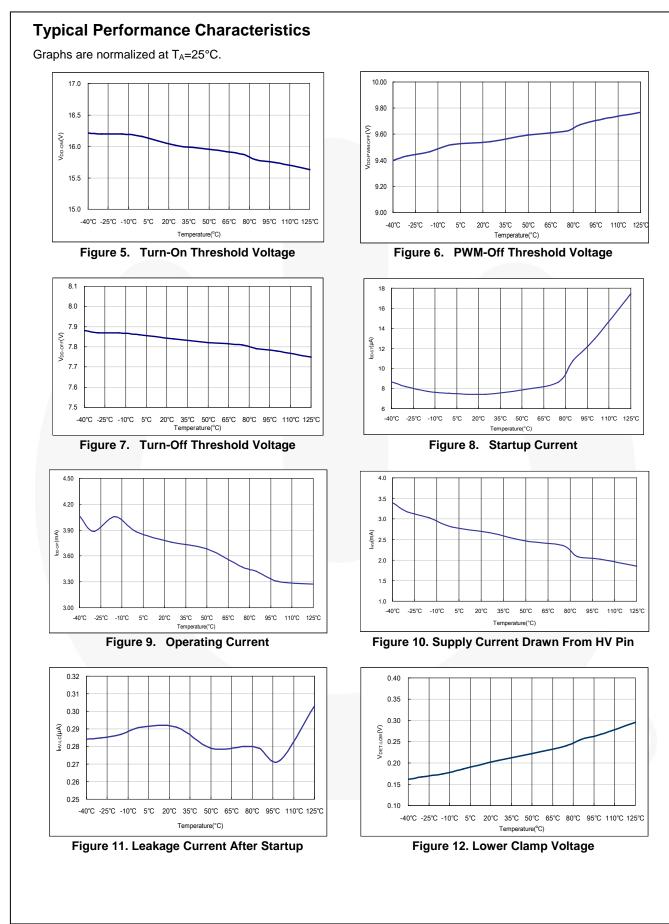
## Electrical Characteristics(Continued)

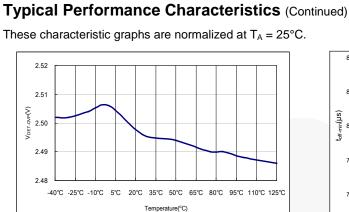
Unless otherwise specified,  $V_{DD}$ =10~25 V,  $T_A$ =-40°C ~125°C ( $T_A$ = $T_J$ ).

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Current S	ense Section					
t <sub>PD</sub>	Delay to Output		20	150	200	ns
M	Limit Voltage on CS Pin for Over-Power	I <sub>DET</sub> < 74.41 μA	0.82	0.85	0.88	V
$V_{LIMIT}$	Compensation	Ι <sub>DET</sub> =550 μΑ	0.380	0.415	0.450	V
M	Slope Compensation <sup>(3)</sup>	t <sub>on</sub> =45 μs		0.3		V
VSLOPE		t <sub>on</sub> =0 µs		0.1		V
t <sub>BNK</sub>	Leading-Edge-Blanking Time (MOS Turns ON)		525	625	725	ns
V <sub>CS-H</sub>	V <sub>CS</sub> Clamped High Voltage once CS Pin Floating	CS Pin Floating	4.5		5.0	V
t <sub>CS-H</sub>	Delay Time once CS Pin Floating	CS Pin Floating	6	150		μs
Internal O	ver-Temperature Protection Section			•		
T <sub>OTP</sub>	Internal Threshold Temperature for OTP <sup>(3)</sup>			+140		°C
T <sub>OTP-HYST</sub>	Hysteresis Temperature for Internal OTP <sup>(3)</sup>			+15		°C

Note:

3. Guaranteed by design.







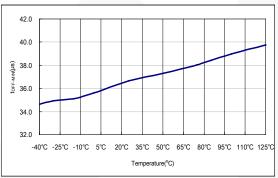
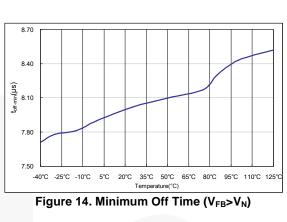


Figure 15. Minimum Off Time (V<sub>FB</sub>=V<sub>G</sub>)



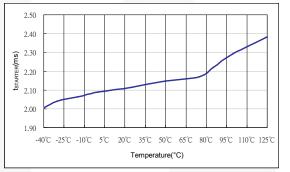


Figure 16. Start Timer (V<sub>FB</sub><V<sub>G</sub>)

#### **Operation Description**

The FAN6300A/H PWM controller integrates designs to enhance the performance of flyback converters. An internal valley voltage detector ensures power system operates at Quasi-Resonant (QR) operation across a wide range of line voltage. The following descriptions highlight some of the features of the FAN6300A/H.

#### **Startup Current**

For startup, the HV pin is connected to the line input or bulk capacitor through an external diode and resistor, R<sub>HV</sub>, which are recommended as 1N4007 and 100 k $\Omega$ . Typical startup current drawn from the HV pin is 1.2 mA and it charges the hold-up capacitor through the diode and resistor. When the V<sub>DD</sub> voltage level reaches V<sub>DD-ON</sub>, the startup current switches off. At this moment, the V<sub>DD</sub> capacitor only supplies the FAN6300A/H to maintain V<sub>DD</sub> until the auxiliary winding of the main transformer provides the operating current.

#### **Valley Detection**

The DET pin is connected to an auxiliary winding of the transformer via resistors of the divider to generate a valley signal once the secondary-side switching current discharges to zero. It detects the valley voltage of the switching waveform to achieve the valley voltage switching. This ensures QR operation, minimizes switching losses, and reduces EMI. Figure 17 shows divider resistors R<sub>DET</sub> and R<sub>A</sub>. R<sub>DET</sub> is recommended as 150 k $\Omega$  to 220 k $\Omega$  to achieve valley voltage switching. When V<sub>AUX</sub> (in Figure 17) is negative, the DET pin voltage is clamped to 0.3 V.

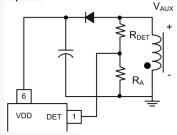
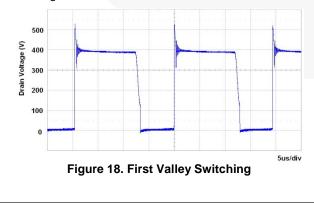


Figure 17. Valley Detect Section

The internal timer (minimum  $t_{OFF}$  time) prevents gate retriggering within 8 µs (3 µs for H version) after the gate signal going-low transition. The minimum  $t_{OFF}$  limit prevents system frequency being too high. Figure 18 shows a typical drain voltage waveform with first valley switching.



#### **Green-Mode Operation**

The proprietary green-mode function provides off-time modulation to linearly decrease the switching frequency under light-load conditions.  $V_{FB}$ , which is derived from the voltage feedback loop, is taken as the reference. In Figure 19, once  $V_{FB}$  is lower than  $V_N$ ,  $t_{OFF-MIN}$  increases linearly with lower  $V_{FB}$ . The valley voltage detection signal does not start until  $t_{OFF-MIN}$  finishes. Therefore, the valley detect circuit is activated until  $t_{OFF-MIN}$  finishes, which decreases the switching frequency and provides extended valley voltage switching. However, in very light load condition, it might fail to detect the valley voltage after the  $t_{OFF-MIN}$  expires. Under this condition, an internal  $t_{TIME-OUT}$  signal initiates a new cycle start after a 9 µs delay (with 5 µs delay for H version). Figure 20 and Figure 21 show the two different conditions.

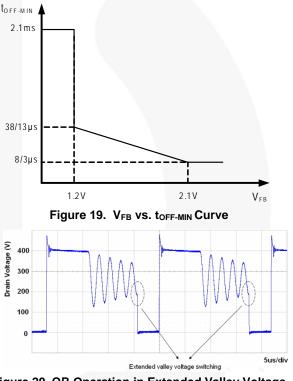
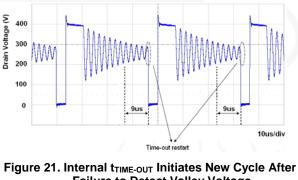
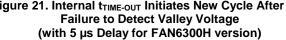


Figure 20. QR Operation in Extended Valley Voltage Detection Mode





#### **Current Sensing and PWM Current Limiting**

Peak-current-mode control is utilized to regulate output voltage and provide pulse-by-pulse current limiting. The switch current is detected by a sense resistor into the CS pin. The PWM duty cycle is determined by this current-sense signal and V<sub>FB</sub>. When the voltage on CS reaches around V<sub>LIMIT</sub> = (V<sub>FB</sub>-1.2)/3, the switch cycle is terminated immediately. V<sub>LIMIT</sub> is internally clamped to a variable voltage around 0.85 V for output power limit.

#### Leading-Edge Blanking (LEB)

Each time the power MOFFET switches on, a turn-on spike occurs on the sense resistor. To avoid premature termination of the switching pulse, lead-edge blanking time is built in. During the blanking period, the current limit comparator is disabled; it cannot switch off the gate driver.

#### **Under-Voltage Lockout (UVLO)**

The turn-on, PWM-off, and turn-off thresholds are fixed internally at 16/10/8 V. During startup, the startup capacitor must be charged to 16 V through the startup resistor to enable the IC. The hold-up capacitor continues to supply  $V_{DD}$  until energy can be delivered from the auxiliary winding of the main transformer.  $V_{DD}$  must not drop below 10 V during this startup process. This UVLO hysteresis window ensures that hold-up capacitor is adequate to supply  $V_{DD}$  during startup.

#### **Gate Output**

The BiCMOS output stage is a fast totem-pole gate driver. Cross conduction has been avoided to minimize heat dissipation, increase efficiency, and enhance reliability. The output driver is clamped by an internal 18 V Zener diode to protect power MOSFET transistors against undesired over-voltage gate signals.

#### **Over-Power Compensation**

To compensate this variation for wide AC input range, the DET pin produces an offset voltage to compensate the threshold voltage of the peak current limit to provide a constant-power limit. The offset is generated in accordance with the input voltage when PWM signal is enabled. This results in a lower current limit at high-line inputs than low-line inputs. At fixed-load condition, the CS limit is higher when the value of  $R_{DET}$  is higher.  $R_{DET}$  also affects the H/L line constant power limit.

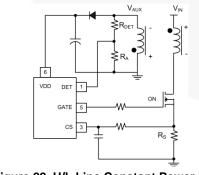


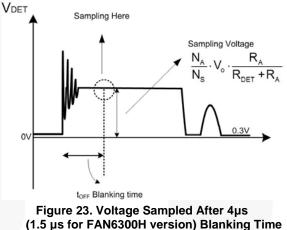
Figure 22. H/L Line Constant Power Limit Compensated by DET Pin

#### **V<sub>DD</sub> Over-Voltage Protection**

 $V_{DD}$  over-voltage protection prevents damage due to abnormal conditions. Once the  $V_{DD}$  voltage is over the  $V_{DD}$  over-voltage protection voltage ( $V_{DD-OVP}$ ) and lasts for  $t_{VDDOVP}$ , the PWM pulse is disabled until the  $V_{DD}$  voltage drops below the UVLO, then starts again.

#### **Output Over-Voltage Protection**

The output over-voltage protection works by the sampling voltage, as shown in Figure 23, after switch-off sequence. A 4  $\mu$ s (1.5  $\mu$ s for H version) blanking time ignores the leakage inductance ringing. A voltage comparator and a 2.5 V reference voltage develop an output OVP protection. The ratio of the divider determines the sampling voltage of the stop gate, as an optical coupler and secondary shunt regulator are used. If the DET pin OVP is triggered, the power system enters latch-mode until AC power is removed.

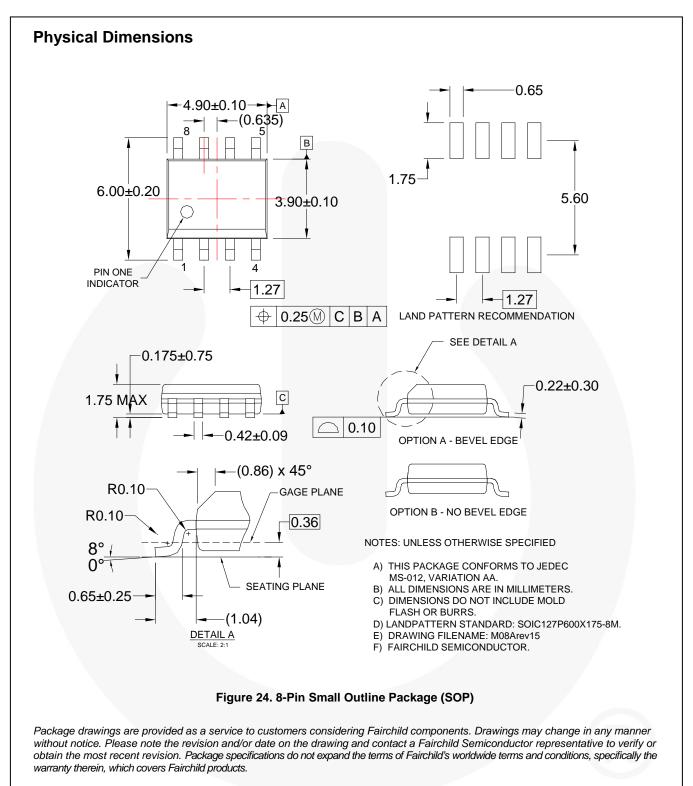


(1.5 μs for FAN6300H version) Blanking Time After Switch-Off Sequence

#### Short-Circuit and Open-Loop Protection

The FB voltage increases every time the output of the power supply is shorted or overloaded. If the FB voltage remains higher than a built-in threshold for longer than  $t_{D-OLP}$ , PWM output is turned off. As PWM output is turned-off, the supply voltage  $V_{DD}$  begins decreasing.

When  $V_{DD}$  goes below the PWM-off threshold of 10 V,  $V_{DD}$  decreases to 8 V, then the controller is totally shut down.  $V_{DD}$  is charged up to the turn-on threshold voltage of 16 V through the startup resistor until PWM output is restarted. This protection feature continues as long as the overloading condition persists. This prevents the power supply from overheating due to overloading.



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